

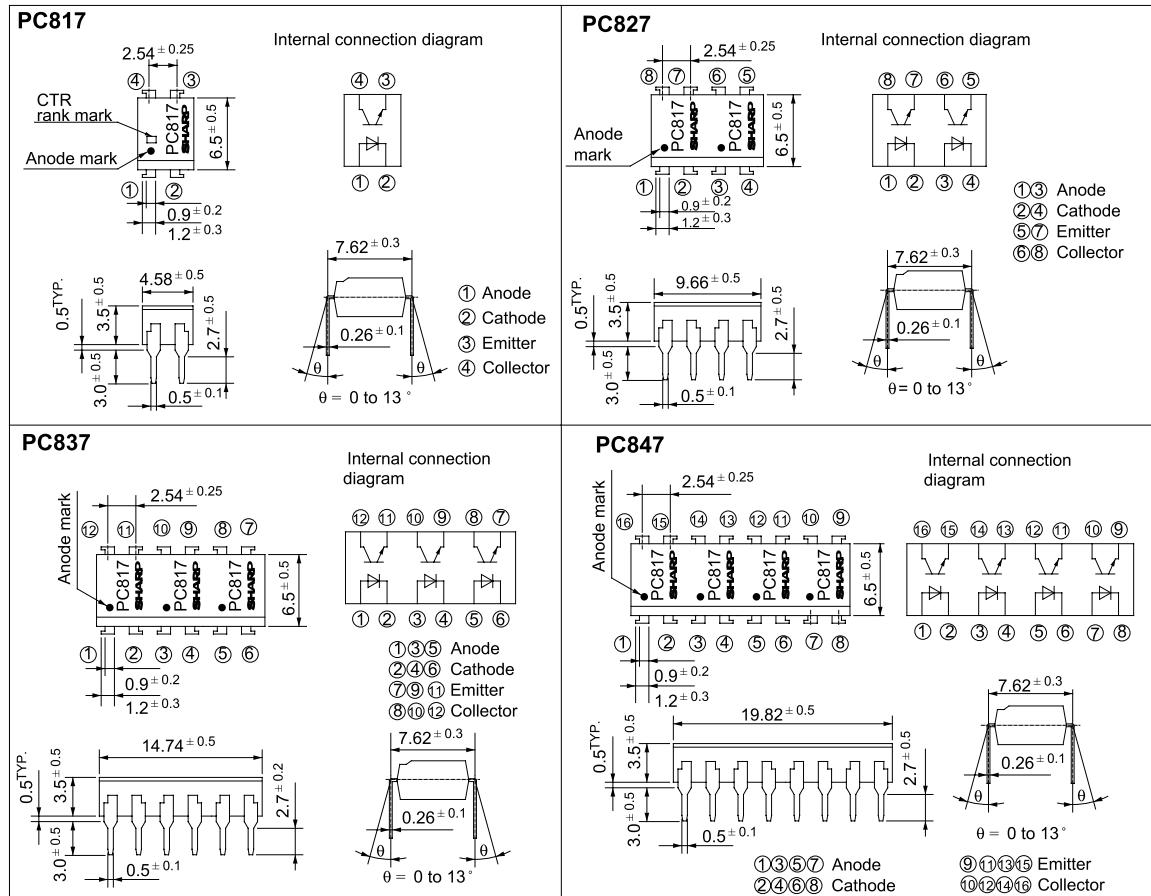
PC817 Series

※ Lead forming type (I type) and taping reel type (P type) are also available. (PC817I/PC817P)
 ※ TÜV (VDE0884) approved type is also available as an option.

■ Features

1. Current transfer ratio
(CTR: MIN. 50% at $I_F = 5\text{mA}$, $V_{CE} = 5\text{V}$)
2. High isolation voltage between input and output ($V_{iso} : 5000\text{V}_{rms}$)
3. Compact dual-in-line package
PC817: 1-channel type
PC827: 2-channel type
PC837: 3-channel type
PC847: 4-channel type
4. Recognized by UL, file No. E64380

■ Outline Dimensions



" In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that occur in equipment using any of SHARP's devices, shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest version of the device specification sheets before using any SHARP's device."

■ Absolute Maximum Ratings

(Ta = 25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I _F	50	mA
	*1Peak forward current	I _{FM}	1	A
	Reverse voltage	V _R	6	V
	Power dissipation	P	70	mW
Output	Collector-emitter voltage	V _{CEO}	35	V
	Emitter-collector voltage	V _{ECO}	6	V
	Collector current	I _C	50	mA
	Collector power dissipation	P _C	150	mW
Total power dissipation		P _{tot}	200	mW
*2Isolation voltage		V _{iso}	5 000	V _{rms}
Operating temperature		T _{opr}	- 30 to + 100	°C
Storage temperature		T _{stg}	- 55 to + 125	°C
*3Soldering temperature		T _{sol}	260	°C

*1 Pulse width <=100μs, Duty ratio : 0.001

*2 40 to 60% RH, AC for 1 minute

*3 For 10 seconds

■ Electro-optical Characteristics

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 20mA	-	1.2	1.4	V
	Peak forward voltage	V _{FM}	I _{FM} = 0.5A	-	-	3.0	V
	Reverse current	I _R	V _R = 4V	-	-	10	μA
	Terminal capacitance	C _t	V = 0, f = 1kHz	-	30	250	pF
Output	Collector dark current	I _{CEO}	V _{CE} = 20V	-	-	10 ⁻⁷	A
Transfer characteristics	*4Current transfer ratio	CTR	I _F = 5mA, V _{CE} = 5V	50	-	600	%
	Collector-emitter saturation voltage	V _{CE(sat)}	I _F = 20mA, I _C = 1mA	-	0.1	0.2	V
	Isolation resistance	R _{ISO}	DC500V, 40 to 60% RH	5 x 10 ¹⁰	10 ¹¹	-	Ω
	Floating capacitance	C _f	V = 0, f = 1MHz	-	0.6	1.0	pF
	Cut-off frequency	f _c	V _{CE} = 5V, I _C = 2mA, R _L = 100Ω, - 3dB	-	80	-	kHz
	Response time	t _r	V _{CE} = 2V, I _C = 2mA, R _L = 100Ω	-	4	18	μs
	Fall time	t _f		-	3	18	μs

*4 Classification table of current transfer ratio is shown below.

Fig. 1 Forward Current vs. Ambient Temperature

Model No.	Rank mark	CTR (%)
PC817A	A	80 to 160
PC817B	B	130 to 260
PC817C	C	200 to 400
PC817D	D	300 to 600
PC817AB	A or B	80 to 260
PC817BC	B or C	130 to 400
PC817CD	C or D	200 to 600
PC817AC	A, B or C	80 to 400
PC817BD	B, C or D	130 to 600
PC817AD	A, B, C or D	80 to 600
PC817	A, B, C, D or No mark	50 to 600

*: 1 or 2 or 3 or 4

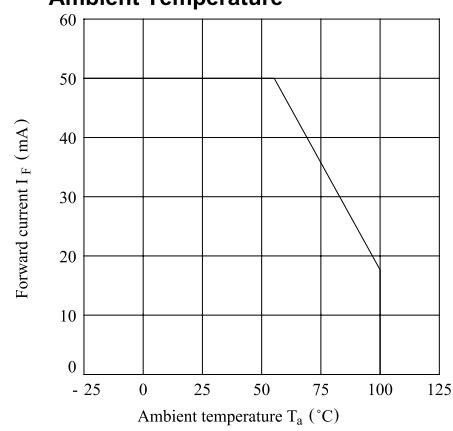


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

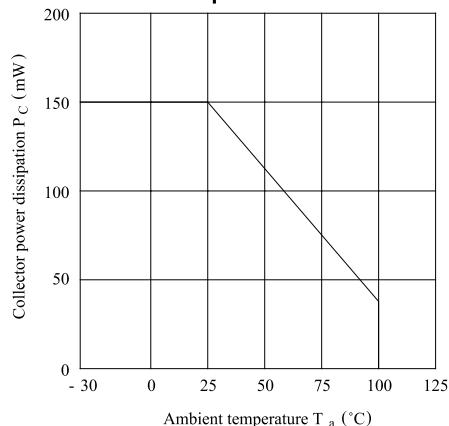


Fig. 4 Current Transfer Ratio vs. Forward Current

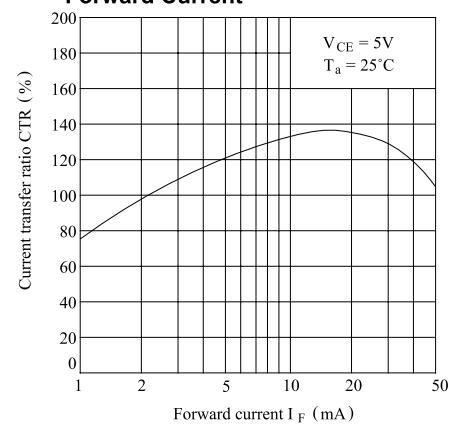


Fig. 6 Collector Current vs. Collector-emitter Voltage

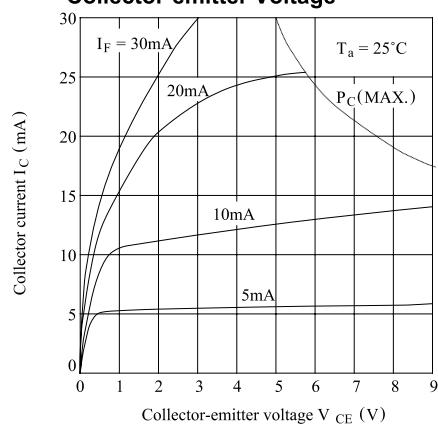


Fig. 3 Peak Forward Current vs. Duty Ratio

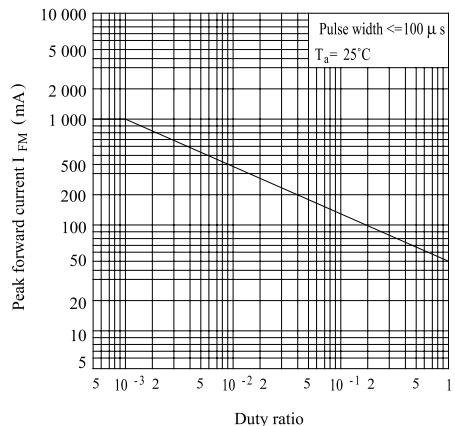


Fig. 5 Forward Current vs. Forward Voltage

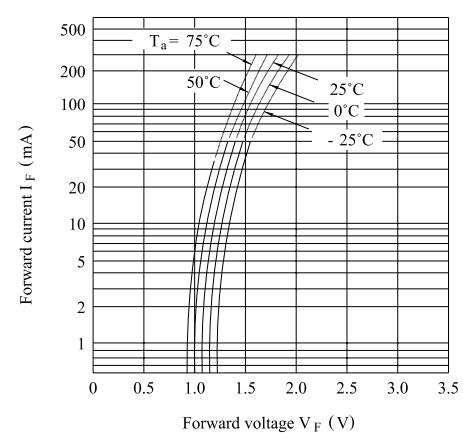


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

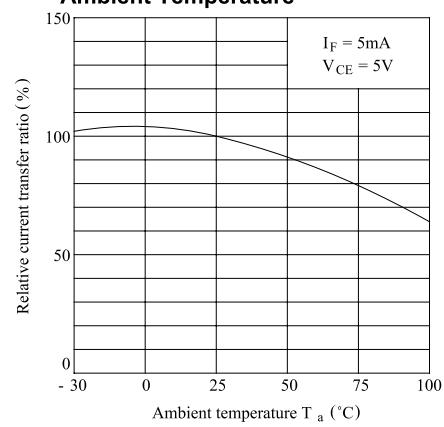


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

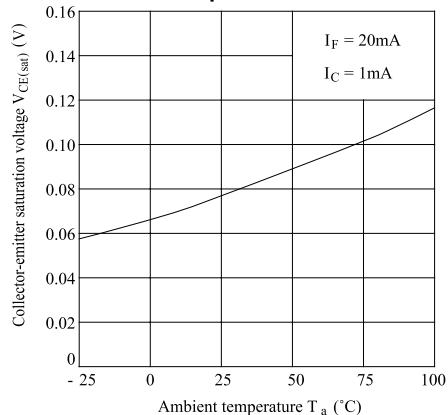


Fig. 9 Collector Dark Current vs. Ambient Temperature

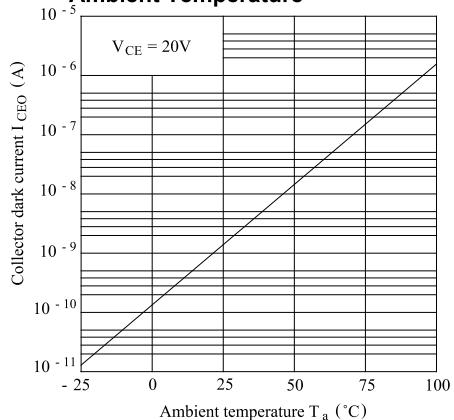


Fig.10 Response Time vs. Load Resistance

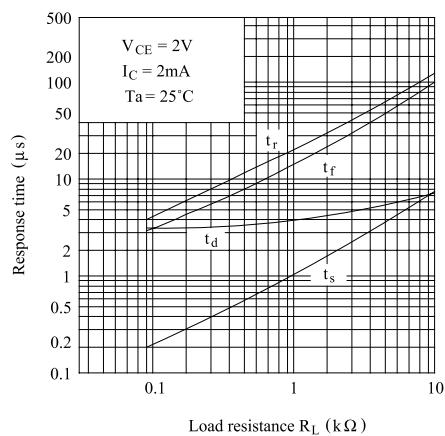
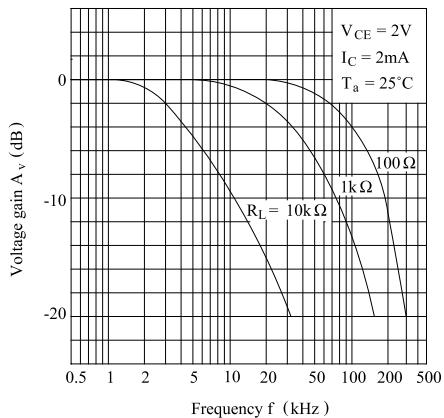
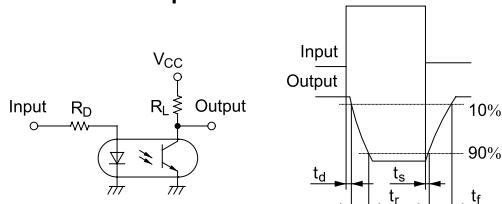


Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response

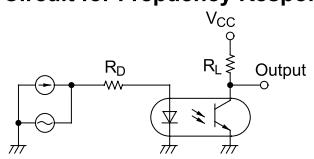
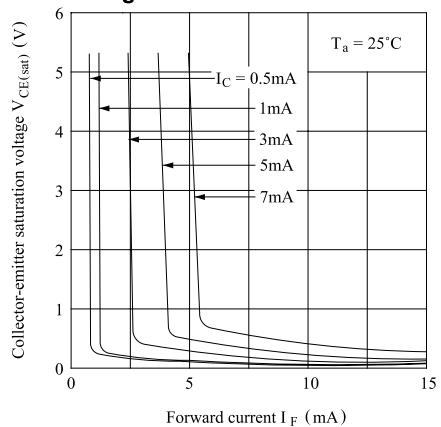


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



● Please refer to the chapter "Precautions for Use"